

## Power Schottky rectifier

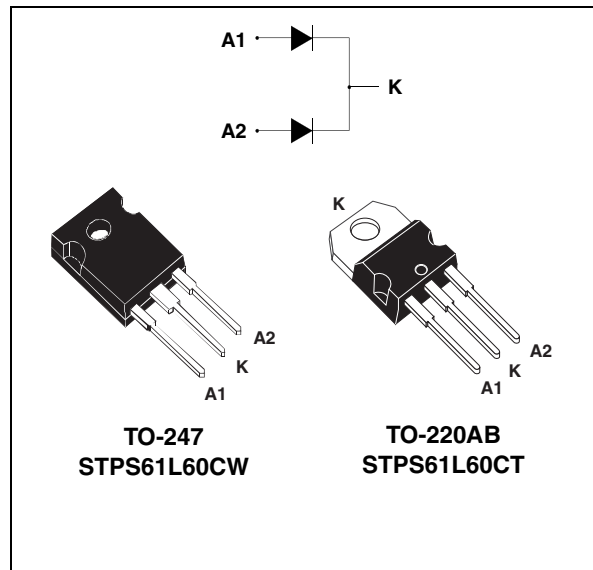
### Features

- High current capability
- Avalanche rated
- Low forward voltage drop current
- High frequency operation

### Description

Dual center tap schottky rectifier suited for high frequency switch mode power supplies.

Packaged in TO-247 and TO-220AB, this device provides desktop SMPS designers with a low forward voltage drop device, and reduced leakage current, with the objective of making the application compliant with environmental care standards, or suitable for 80+ requirements.



**Table 1. Device summary**

$I_{F(AV)}$	2 x 30 A
$V_{RRM}$	60 V
$T_j$ (max)	150 °C
$V_F$ (typ)	0.560 V

# 1 Characteristics

**Table 2. Absolute ratings (limiting values per diode at 25 °C unless otherwise specified)**

Symbol	Parameter			Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage			60	V
I <sub>F(RMS)</sub>	RMS forward current			50	A
I <sub>F(AV)</sub>	Average forward current $\delta = 0.5$	T <sub>c</sub> = 125 °C T <sub>c</sub> = 120 °C	Per diode Per device	30 60	A
I <sub>FSM</sub>	Surge non repetitive forward current	t <sub>p</sub> = 10 ms sinusoidal	TO-247 TO-220AB	530 400	A
P <sub>ARM</sub>	Repetitive peak avalanche power	t <sub>p</sub> = 1 $\mu$ s T <sub>j</sub> = 25 °C		11500	W
T <sub>stg</sub>	Storage temperature range			-65 to + 175	°C
T <sub>j</sub>	Maximum operating junction temperature <sup>(1)</sup>			150	°C

1.  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  condition to avoid runaway for a diode on its own heatsink

**Table 3. Thermal resistances**

Symbol	Parameter			Value	Unit
R <sub>th(j-c)</sub>	Junction to case	TO-247	Per diode Total	0.95 0.6	°C/W
		TO-220AB	Per diode Total	1.1 0.7	
R <sub>th(c)</sub>	Coupling	TO-247		0.25	
		TO-220AB		0.3	

When the diodes 1 and 2 are used simultaneously :

$$\Delta T_j(\text{diode 1}) = P(\text{diode1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode 2}) \times R_{th(c)}$$

**Table 4. Static electrical characteristics (per diode)**

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>	-	-	0.8	mA
		T <sub>j</sub> = 125 °C		-	150	350	
V <sub>F</sub> <sup>(2)</sup>	Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 5 A	-	0.360	-	V
		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 5 A	-	0.255	-	
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 15 A	-	0.460	0.540	
		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 15 A	-	0.415	0.480	
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 30 A	-	0.580	0.660	
		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 30 A	-	0.560	0.620	

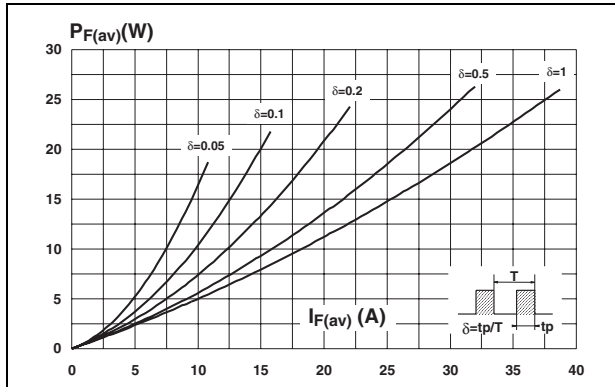
1. Pulse test: t<sub>p</sub> = 5 ms,  $\delta < 2\%$

2. Pulse test: t<sub>p</sub> = 380  $\mu$ s,  $\delta < 2\%$

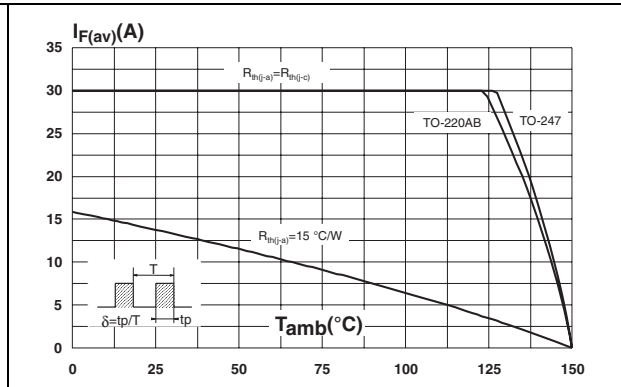
To evaluate the conduction losses use the following equation:

$$P = 0.44 \times I_{F(AV)} + 0.006 \times I_{F(RMS)}^2$$

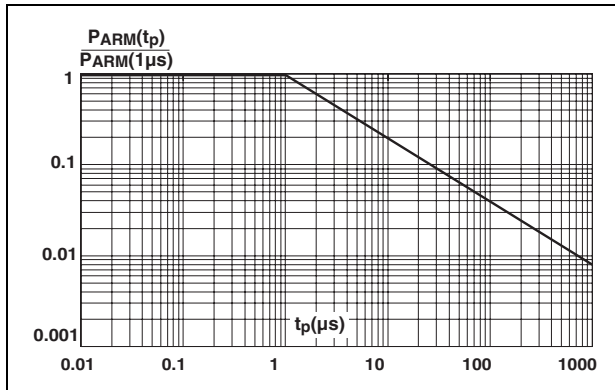
**Figure 1. Average forward power dissipation vs. average forward current (per diode)**



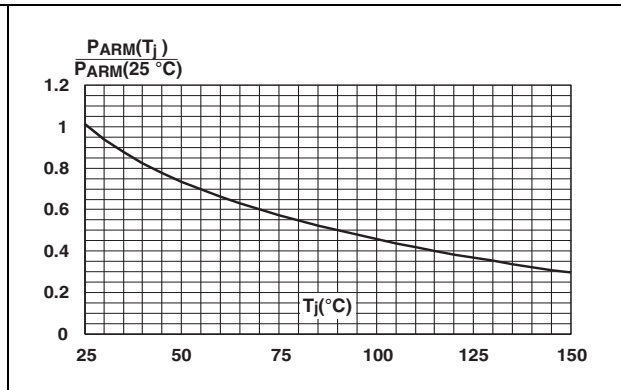
**Figure 2. Average forward current vs. ambient temperature ( $\delta = 0.5$ , per diode)**



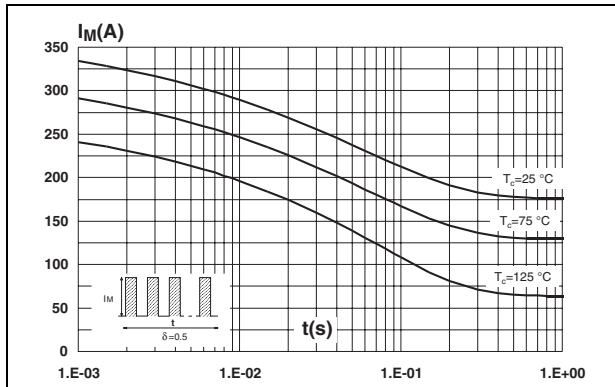
**Figure 3. Normalized avalanche power derating vs. pulse duration**



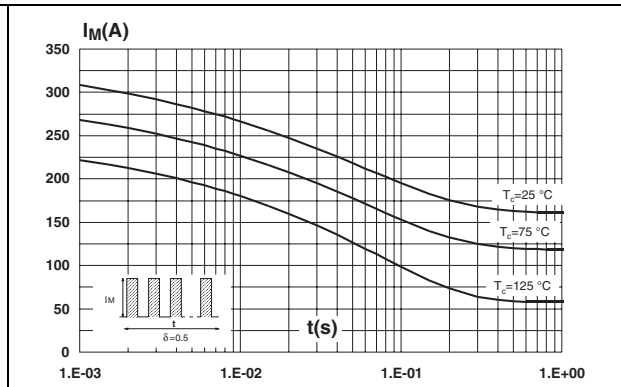
**Figure 4. Normalized avalanche power derating vs. junction temperature**



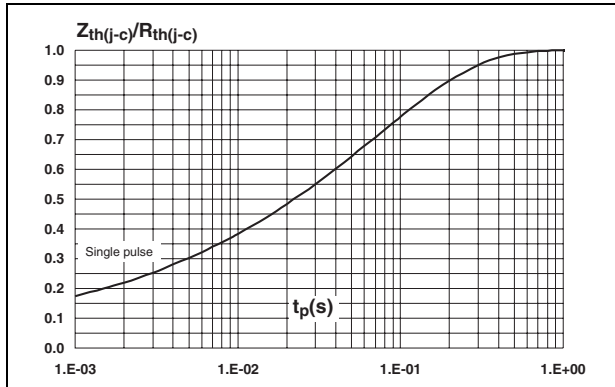
**Figure 5. Non repetitive surge peak forward current vs. overload duration (max. values, per diode, TO-247)**



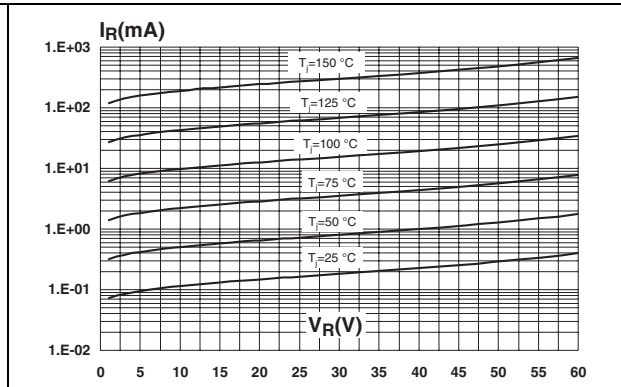
**Figure 6. Non repetitive surge peak forward current vs. overload duration (max. values, per diode, TO-220AB)**



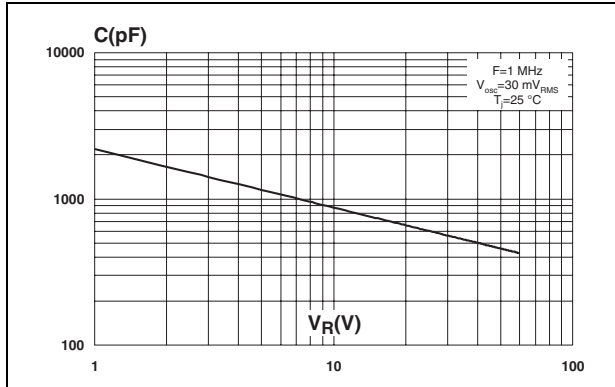
**Figure 7. Relative variation of thermal impedance junction to case vs. pulse duration**



**Figure 8. Reverse leakage current vs. reverse voltage applied (typical values, per diode)**



**Figure 9. Junction capacitance vs. reverse voltage applied (typical values, per diode)**



**Figure 10. Forward voltage drop vs. forward current (per diode)**

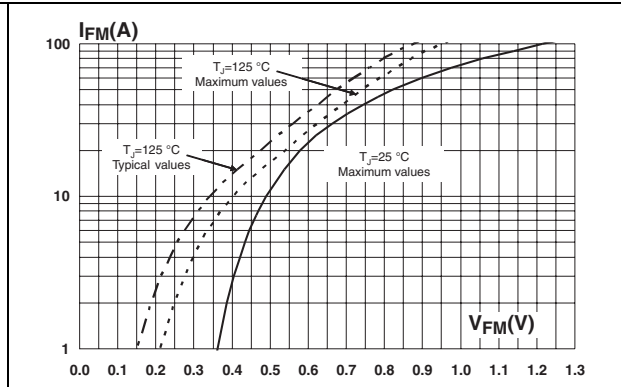
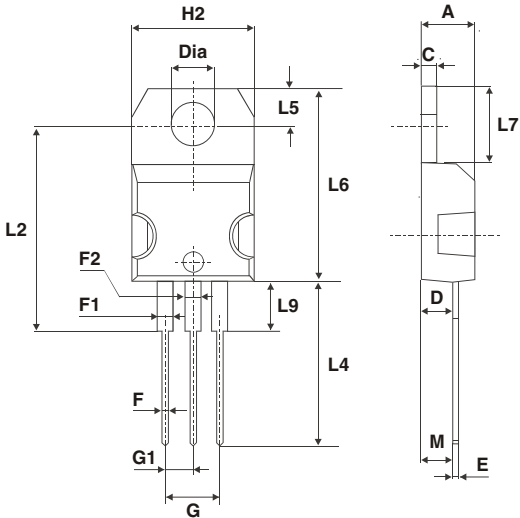




Table 6. TO-220AB dimensions



Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

### 3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS61L60CW	STPS61L60CW	TO-247	4.4 g	30	Tube
STPS61L60CT	STPS61L60CT	TO-220AB	2.23 g	30	Tube

### 4 Revision history

Table 8. Document revision history

Date	Revision	Changes
18-May-2009	1	Initial release

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